

DIO7110 True Monolithic Li-Ion/Polymer Battery Protector in Tiny Thin Package

Features

- Ultra Compact Protection Solution
- 56mΩ Pass Resistance
- 1.3µA Operation Current
- Factory Programmable OVP Threshold Options 4.2V to 4.55V with 0.05V per Step
- Over-Charge/Discharge Current Protection 4 Threshold Combination Options
- Battery Under-Voltage Protection 2.4V/2.5V/2.8V/3.0V Options
- 100nA Deep Discharging Shutdown
- OV Battery Charge Function
- With High Efficiency Charging Mode
- Input Surge Clamping
- Input Over-Voltage Safe
- Load Short-Circuit Safe
- Reverse Polarity Battery Safe
- Input Reversed-Attaching Safe
- Available in Green DFN1.5*2-6 Package

Applications

- Wireless Chargers
- Portable Equipment
- Communication Systems

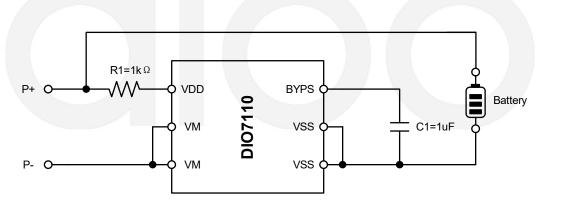
Descriptions

The DIO7110 is designed for primary protection of Li-lon/Polymer rechargeable cells. The product integrates all the protections required for safe operation of polymer rechargeable cells. The device is packaged in a tiny and thin package. Its small solution size leaves more space for fitting the battery cell into a given cavity for small size wearable devices.

The DIO7110 integrates all the protections and the required low on-resistance disconnect switch on one die. The protection features include charging and discharging protection, detection and protection of a cell in over-charging, overdischarging, over-current, and battery undervoltage. The low standby current drains little current from cell while in storage.

The DIO7110 operates in -40°C to 85°C temperature range, and is in a thin and low profile DFN1.5*2-6 package. This package is convenient for small cell packing design.

Typical Applications







Ordering Information

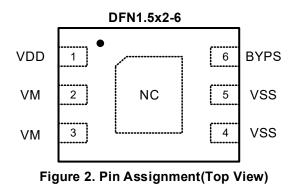
Order Part Number	Top Marking			TA		Package				
DIO7110aaabcLD6	DXbc	Greer	1	-40 to 85°C	DFN	1.5*2-6	Tape & R	eel, 3000		
Order Part Number: DIO7110aaabal D6										
Order Part Number: DIO7110aaabcLD6 Over Voltage Threshold Options										
Option Code " aaa '	" 420	425	430	435	440	445	450	455		
Over Voltage Thresh V _{OV} (V)	old 4.20	4.25	4.30	4.35	4.40	4.45	4.50	4.55		
Under Voltage Thresh	old Options									
Option Code " b "	A		В			С		D		
Under Voltage Thresh V _{UV} (V)	nold 2.4	4	2.5		2	2.8		3.0		
Current Threshold Co	ombination Option	s								
Option Code " c "	A			В		С		D		
Over Charge Curre I _{oc} (A)	nt 1.3	1.33		0.66		1.33		0.66		
Over Discharge Curr I _{OD} (A)	ent 1.3	33	1.33		0.66		0.66			
Short Circuit Current	(A) 2.6	8	2.68		1.96		1.96			

Marking Definition: DXbc										
Product code										
Option Code " D "	Product co	Product code								
Over Voltage Threshold Options										
Option Code " X "	2	3	4	5	6	7	8	9		
Over Voltage Threshold V _{OV} (V)	4.20	4.25	4.30	4.35	4.40	4.45	4.50	4.55		
Under Voltage Threshold C	ptions									
Option Code " b "	Option Code "b" A B C D									
Under Voltage Threshold V _{UV} (V)	2	2.4 2.5 2.8 3.0						.0		



Current Threshold Combination Options								
Option Code " c "	А	В	С	D				
Over Charge Current I _{OC} (A)	1.33	0.66	1.33	0.66				
Over Discharge Current I _{OD} (A)	1.33	1.33	0.66	0.66				
Short Circuit Current (A)	2.68	2.68	1.96	1.96				

Pin Assignment



Pin Descriptions

Pin	Name	Туре	Description
1	VDD	Р	Power input and output, the battery pack positive connection. The default sate after battery attached is Closed or locked-off, dependent on the external circuitry.
2.3	VM	Р	Power input and output, the battery pack cathode. Short this pin to the VSS pin to release off the lock-open state, and make the output path closed.
4,5	VSS	G	Ground of internal circuit. Connect to battery cathode end.
6	BYPS	I/O	Bypass pin and disconnection locked-off triggering input. Place a 1uF capacitor between this and VSS pin. Shorting this pin to VM pin momentarily places the circuit into locked-open state.
Thermal Pad	NC	NC	Not connected internally. Can be connected to VSS.



Absolute Maximum Ratings

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter	Symbol	Rating	Unit
Supply Voltage	V _{DD}	-0.3 to 8	V
V _M Pin Input Voltage	V _M	V_{DD} -10 to V_{DD} +0.3	V
Supply Voltage to VM Pin Voltage	V_{DD} - V_{M}	-0.3 to 10	V
Power Consumption at T _A =25℃	Pd	400	mW
Operating Temperature Range	T _A	-40 to 85	°C
Storage Temperature Range	T _{STG}	-55 to 125	°C
Maximum Junction Temperature	TJ	125	°C
Lead temperature (Soldering, 10 sec)	TL	260	°C
Package thermal resistance (junction to ambient)	Θ _{JA}	240	°C/W
ESD Susceptibility	HBM	6000	V

Recommend Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Symbol	Rating	Unit
Battery Voltage Range	V _{DD} -V _{SS}	0 to 5.5	V
VM Voltage Range	V _{DD} -V _M	V_{DD} -5 to V_{DD} +0.3	V
Operating Temperature Range	T _A	-40 to 85	°C



Electrical Characteristics

 T_A = 25°C, V_{BAT} = 3.6V, unless otherwise noted. Specifications subject to change without notice.

Parameter	Symbol	Con	Conditions		Тур	Мах	Uni
			T _A =25°C	4.165		4.235	
		DIO7110-420	T _A =-20°C to 55°C	4.152	4.200	4.248	
			T _A =-40°C to 85°C	4.100		4.300	
			T _A =25°C	4.215		4.285	
		DIO7110-425	T _A =-20°C to 55°C	4.202	4.250	4.298	I
			T _A =-40°C to 85°C	4.150		4.350	
			T _A =25°C	4.265		4.335	
		DIO7110-430	T _A =-20°C to 55°C	4.252	4.300	4.348	
			T _A =-40°C to 85°C	4.200		4.400	
			T _A =25°C	4.315		4.385	
		DIO7110-435	T _A =-20°C to 55°C	4.302	4.350	4.398	
Over-Charge Voltage			T _A =-40°C to 85°C	4.215 4.285 $^{\circ}$ C 4.202 4.250 4.298 $^{\circ}$ C 4.150 4.350 $^{\circ}$ C 4.265 4.300 4.335 $^{\circ}$ C 4.265 4.300 4.348 $^{\circ}$ C 4.200 4.300 4.348 $^{\circ}$ C 4.200 4.300 4.348 $^{\circ}$ C 4.200 4.300 4.398 $^{\circ}$ C 4.302 4.350 4.398 $^{\circ}$ C 4.302 4.350 4.435 $^{\circ}$ C 4.302 4.400 4.448 $^{\circ}$ C 4.302 4.400 4.448 $^{\circ}$ C 4.300 4.485 4.500 $^{\circ}$ C 4.300 4.485 4.500 $^{\circ}$ C 4.402 4.450 4.485 $^{\circ}$ C 4.350 4.550 4.598 $^{\circ}$ C 4.502 4.500 4.598 $^{\circ}$ C 4.502 4.598 4.650 $^{\circ}$ C 4.502 4.650 4.650			
Threshold	Vov	DIO7110-440	T _A =25°C	4.365		4.435	
			T _A =-20°C to 55°C	4.352	4.400	4.448	
			T _A =-40°C to 85°C	4.300		4.500	
		DIO7110-445 T _A =-20°C to 55°C 4.402	T _A =25°C	4.415	4.450	4.485	
			T _A =-20°C to 55°C	4.402		4.498	
			4.350		4.550		
		DIO7110-450	T _A =25°C	4.465	4.500	4.535	-
			T _A =-20°C to 55°C	5.452		4.548	
			T _A =-40°C to 85°C	4.400		4.600	
		DIO7110-455	T _A =25°C	4.515	4.550	4.585	
			T _A =-20°C to 55°C	4.502		4.598	
			T _A =-40°C to 85°C	4.450		4.650	
OV Release Hysteresis	Vovhys	Voltage lower than	the battery voltage		200		m
		<u> </u>	T _A =25°C	2.362		2.438	- V
		DIO7110A_	T _A =-20°C to 55°C	2.350	2.400	2.450	
			T _A =-40°C to 85°C	2.290	-	2.510	
			T _A =25°C	2.462		2.538	
		DIO7110B_	T _A =-20°C to 55°C	2.450	2.500	2.550	
Battery Under Voltage			T _A =-40°C to 85°C	2.390		2.610	
Threshold	V _{UV}		T _A =25°C	2.762		2.838	
		DIO7110C_	T _A =-20°C to 55°C	2.750	2.800	2.850	
			T _A =-40°C to 85°C	2.690	2.000	2.910	
			T _A =25°C	2.962		3.038	
		DIO7110D_	T _A =-20°C to 55°C	2.950	3.000	3.050	
			T_{A} =-40°C to 85°C	2.890	3.000	3.110	
UV Release Hysteresis	VUVHYS				100	-	m\



		DIO7110C	T _A =25°C	0.50	0.00	0.82	
		D	T _A =-20°C to 55°C	0.43	0.66	0.94	А
Over-Discharge Current	I _{OD}	DIO7110A	T _A =25°C	1.00	4.00	1.66	
		B	T _A =-20°C to 55°C	0.85	1.33	1.91	
		DIO7110B	T _A =25°C	0.35	0.00	1.00	
Over Oberne Overset		D	T _A =-20°C to 55°C	0.26	0.66	1.25	A
Over-Charge Current	loc	DIO7110A	T _A =25°C	0.75	4.00	2.00	
		C	T _A =-20°C to 55°C	0.56	1.33	2.50	
Dees Desistance	P	T _A =25°C			FC	64	mΩ
Pass Resistance	R _P	T _A =-20°C to 55°C			56	78	
Operating Current	I	T _A =25°C		1.0	1.8	uA	
Operating Current	I _{OP}	T _A =-20°C to 55°C			1.3	2.8	uA
Shutdown Current	I _{SHDN}					0.1	uA
Over-Voltage Detection Delay	t _{OVPD}				160		ms
Under-Voltage Detection Delay	t _{UVPD}				40		ms
Over-Discharge Current	+				10		ma
Detection Delay	t _{ODD}				10		ms
Over-Charge Current Detection	t _{ocp}				10		ms
Delay	LOCD				10		1115
Discharge Short-Circuit	tocsp				0.2		ms
Detection Delay	LOCSD				0.2		1113
		DIO7110A			2x I _{OD}		
Discharge Short-Circuit Current	I _{SC}	B			27 100		А
	130	DIO7110C			3x Iop		
		D					
Over Temperature Pretection	T _{OTP}				150		°C
Over Temperature Pretection	T _{OTPHYS}				20		°C
Hysteresis	0.1110						-

Application Information

The DIO7110 monitors voltage and current applied on battery cell connected between VDD and VSS, and opens the connection between battery and pack terminal with its internal switches when a fault condition is detected.

Normal Condition

Battery voltage is between the over discharge voltage threshold and over charge voltage threshold, and no overcharge current and over discharge current is detected, charging and discharging can be carried out freely, this condition is called the normal operating condition.

Over Charge Condition

When battery voltage reaches over-voltage threshold (V_{OV}) and keeps for over-charge detection delay time (T_{OVPD}), the charging path is open circuited. The path closes again in the following two cases:

- (1) If VM pin's voltage is less than 0.35V (typical), when battery voltage falls back about V_{OVHYS} below the battery voltage, then over charge condition is released.
- (2) If VM pin's voltage is above 0.35V (typical), when battery voltage falls back about V_{OV} , then over charge condition is released.

Over Discharge Condition

In order to protect the battery from over discharging when battery voltage falls below V_{UV} , the discharge path is open circuited and the DIO7110 enters into shutdown sleeping mode in order to further reduce the current consumption, which helps to keep the battery from harmful exhausted conditions as long as possible. The path closes again when a charging supply is applied or the battery voltage rises to about 100mV above the V_{UV} threshold.

In the over discharge condition, the battery charges through the internal power MOSFET body diode. All internal circuitry is OFF. Discharge is not allowed. When battery voltage rises above under-voltage threshold, the chip enters normal operation and charge and discharge modes are allowed.

Over-discharge Current Condition

When over-discharging current condition occurs and keeps for over-discharge current detection delay (T_{OD}), the discharging path opens, and the VM pin is shorted to VSS through internal resistance. The path closes again by load removed or connecting a charger.

Over-charge Current Condition

During a charging condition, if charging current is above 400mA and keeps for 10ms (typical) delay, DIO7110 enters into High Efficiency Charging Mode, and when the charging current increase further, an over-charging current is identified, the DIO7110 enters into the locked-off state. This state can be reset by charger removal (pack removal).

Short-circuit protection

When discharge current exceeds 3 times (DIO7110___C/D) or 2 times (DIO7110___A/B) of the over-current threshold, discharging path disconnects instantly in t_{OCSD} , in order to protect the battery from potential over



current stress. After this disconnection, the DIO7110 stays in the locked-off non-conducting state until being reactivated.

0V Battery Charge Function

This function is used to recharge the connected battery whose voltage is 0V due to the self-discharge. When the 0V battery charge starting charger voltage or higher is applied between VDD and VM Pins by connecting a charger, In this state the battery charges through the internal power MOSFET body diode. When the battery voltage rises to about 100mV above the Over-discharge Detection Voltage (V_{UV}), the IC enters the normal condition.

Battery delivery state

It is recommended to deliver a battery pack in lock-off non-conducting state to avoid unintentional shorting in production handling or transportation. Places the DIO7110 into a lock-off state after battery attachment by momentarily shorting BYPS and VM.

Pack activation

In order to release the pack from lock-off state and to place it into a conducting state, apply a charging input or connect VM to VSS momentarily.

Select Protection Parameters

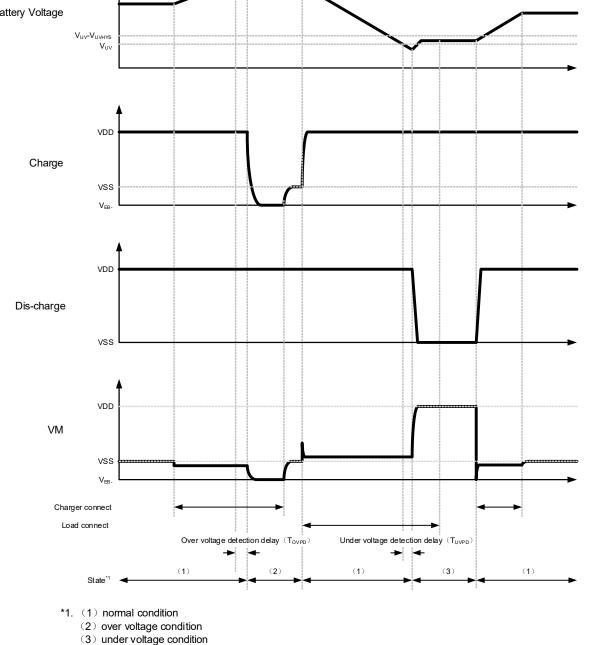
Battery models from different vendors may be customized for different applications. Consult the battery vendor for protection limits for specific battery model. Parameters for the protection circuit and of the charger circuit affecting same variables should be set for proper charge or discharge protection sequence. For example, the over-voltage threshold of the battery should be 50mV~100mV higher than constant voltage threshold of the charger.

Cautions on parameter misalignment

If the V_{OV} is lower than the battery charger's full of charge voltage, the protection circuit cuts off the battery charge path before the battery is fully charged, and turns into the non-conductive lock-off state; if the I_{OC} is lower than the charger's charge current, the protection circuit also turns itself into the lock-off state. In either V_{OV} or I_{OC} , the charger input should be removed and then re-applied for activating the protection circuit from the lock-off state to the conducting state. If the charger is not removed after a V_{OV} or I_{OV} event, the battery will not be charged even if the battery voltage depletes.



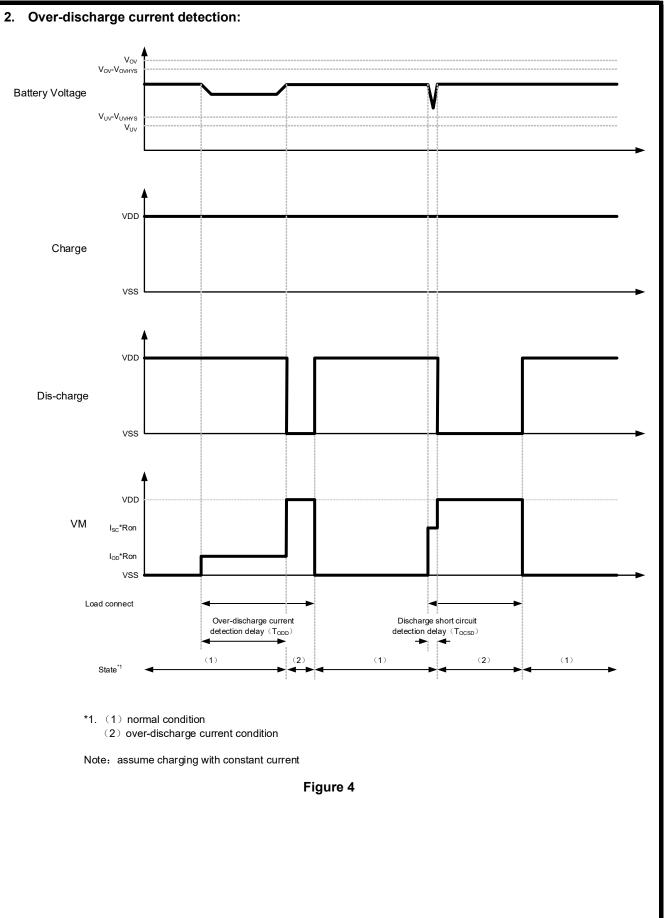
Operation Timing Chart 1. Over-charge and over-discharge detection: Nove-Voltage



Note: assume charging with constant current

Figure 3







DIO7110 3. Over-charge current detection: V_{OV} V_{OV}-V_{OVHYS} Battery Voltage V_{UV}-V_{UVHYS} V_{UV} VDD Charge vss V_{EB}. VDD Dis-charge vss VDD VM vss V_{EB}. Charger connect Load connect Over-charge current detection delay (T_{OCD}) $\begin{array}{l} \text{Over-charge current} \\ \text{detection delay} \ (T_{\text{OCD}}) \end{array}$ Under voltage detection delay (T_{UVPD}) (1) (2) (1) (3) (1) (2) State *1. (1) normal condition (2) over-charge current condition (3) under voltage condition Note: assume charging with constant current Figure 5



CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as, cell phone, handheld products, laptop, and medical equipment and so on. Dioo's product families include analog signal processing and amplifying, LED drivers and charger IC. Go to <u>http://www.dioo.com</u> for a complete list of Dioo product families.

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